

# RJK1003DPP-E0

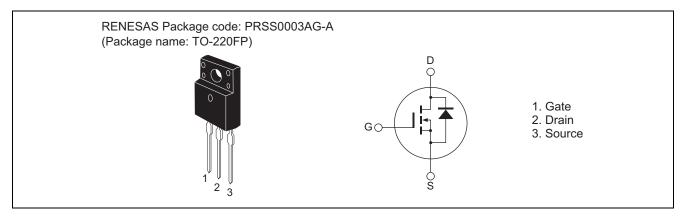
N-Channel MOS FET 100 V, 50 A, 11 m $\Omega$ 

R07DS0627EJ0200 Rev.2.00 Oct 17, 2012

## Features

- High speed switching
- Low drive current
- Low on-resistance  $R_{DS(on)} = 8.8 \text{ m}\Omega \text{ typ.}$  (at  $V_{GS} = 10 \text{ V}$ )
- Package TO-220FP

#### Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	ID	50	A
Drain peak current	I <sub>D (pulse)</sub> Note1	150	A
Body-drain diode reverse drain current	I <sub>DR</sub>	50	A
Avalanche current	I <sub>AP</sub> Note2	25	A
Avalanche energy	E <sub>AS</sub> <sup>Note2</sup>	63	mJ
Channel dissipation	Pch Note3	25	W
Channel to case thermal impedance	θch-c	5.0	°C/W
Channel temperature	Tch	150	٥C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at L = 100  $\mu H$  , Tch = 25°C, Rg  $\geq 50 \Omega,$ 

3. Tc = 25°C



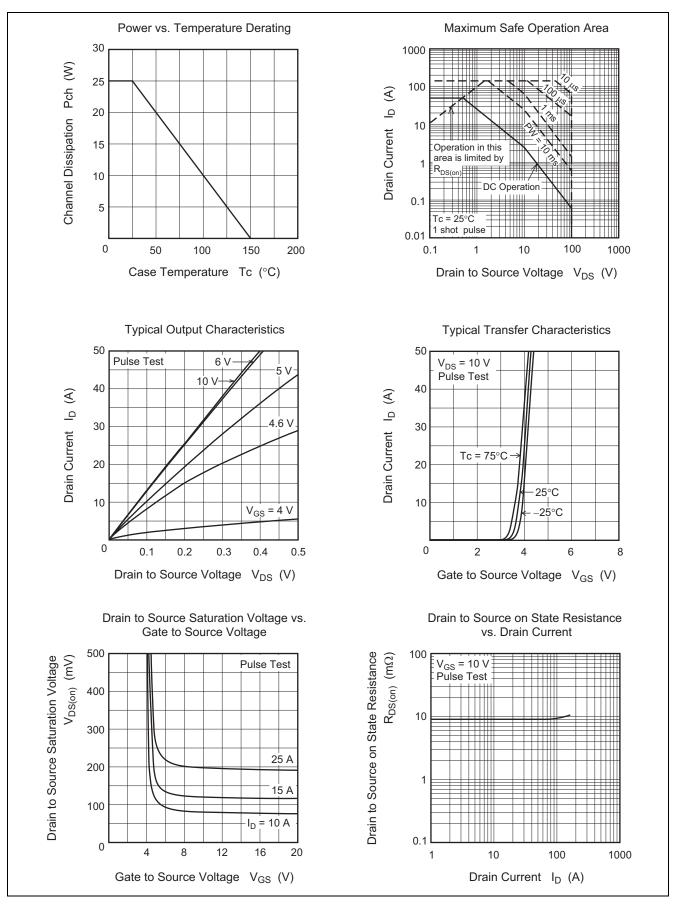
## **Electrical Characteristics**

			1			$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	100	—	—	V	$I_{D} = 10 mA, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	—	—	±0.1	μA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	—	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	8.8	11.0	mΩ	$I_D = 25 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance						
Forward transfer admittance	y <sub>fs</sub>	—	100	—	S	$I_D = 25 \text{ A}, V_D = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	—	4150	—	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	—	660	—	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	—	160	—	pF	
Gate Resistance	Rg	_	1.6	—	Ω	
Total gate charge	Qg	_	59	—	nC	$V_{DD}$ = 50 V $V_{GS}$ = 10 V, $I_{D}$ = 25 A
Gate to source charge	Qgs	_	20	—	nC	
Gate to drain charge	Qgd	_	12	—	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	30	—	ns	$\label{eq:GS} \begin{array}{l} V_{GS} = 10 \ V \\ I_D = 25 \ A \\ V_{DD} \cong 30 \ V \\ Rg = 4.7 \ \Omega \end{array}$
Rise time	tr	_	9	—	ns	
Turn-off delay time	t <sub>d(off)</sub>	_	60	—	ns	
Fall time	t <sub>f</sub>	_	10	_	ns	
Body-drain diode forward voltage	V <sub>DF</sub>	_	0.85	1.5	V	$I_F = 50 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	55	—	ns	$I_F = 50 \text{ A}, V_{GS} = 0$
						di <sub>F</sub> /dt = 100 A/µs

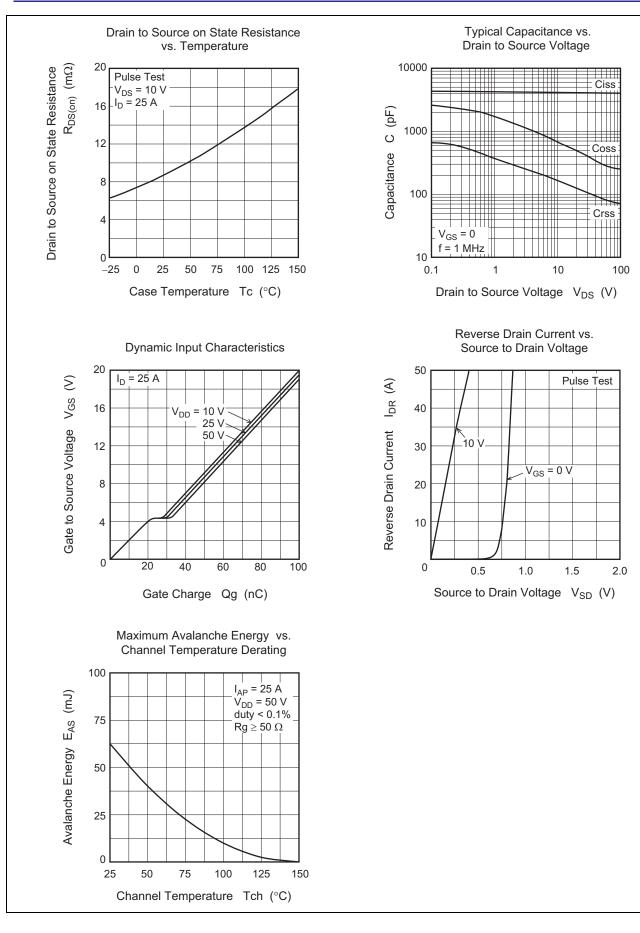
Notes: 4. Pulse test

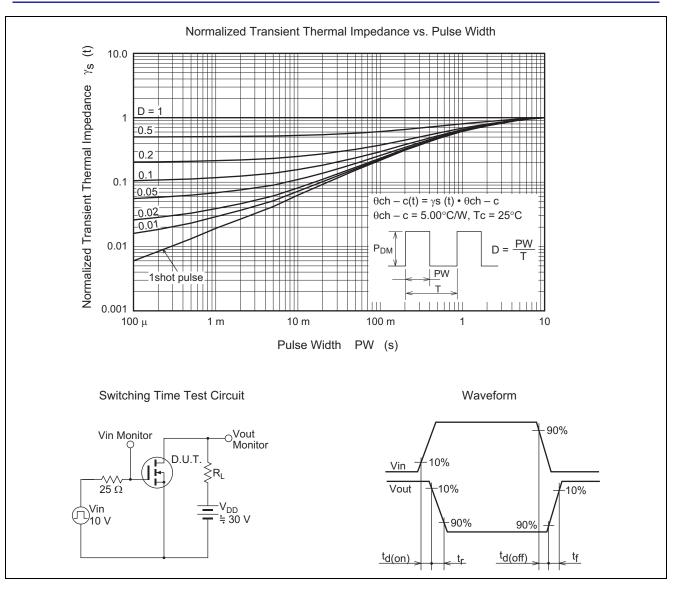


#### **Main Characteristics**



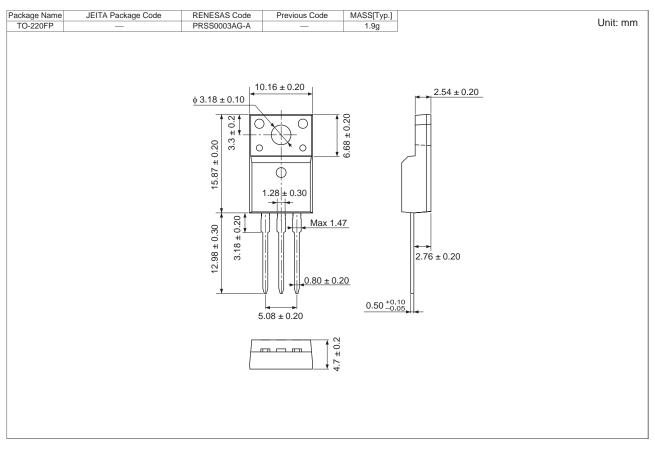








## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK1003DPP-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".



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